

March 2016



FQB34P10

P-Channel QFET® MOSFET

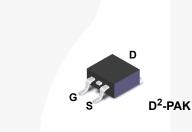
100 V, -33.5 A, 60 mΩ

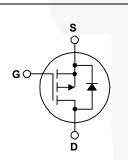
Description

This P-Channel enhancement mode power MOSFET is • -33.5 A, -100 V, $R_{DS(on)}$ = 60 m Ω (Max.) @ V_{GS} = .10 V, produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, audio amplifier, DC motor control, and variable switching power applications.

Features

- I_D = -16.75 A
- Low Gate Charge (Typ. 85 nC)
- Low Crss (Typ. 170 pF)
- 100% Avalanche Tested
- · 175°C Maximum Junction Temperature Rating





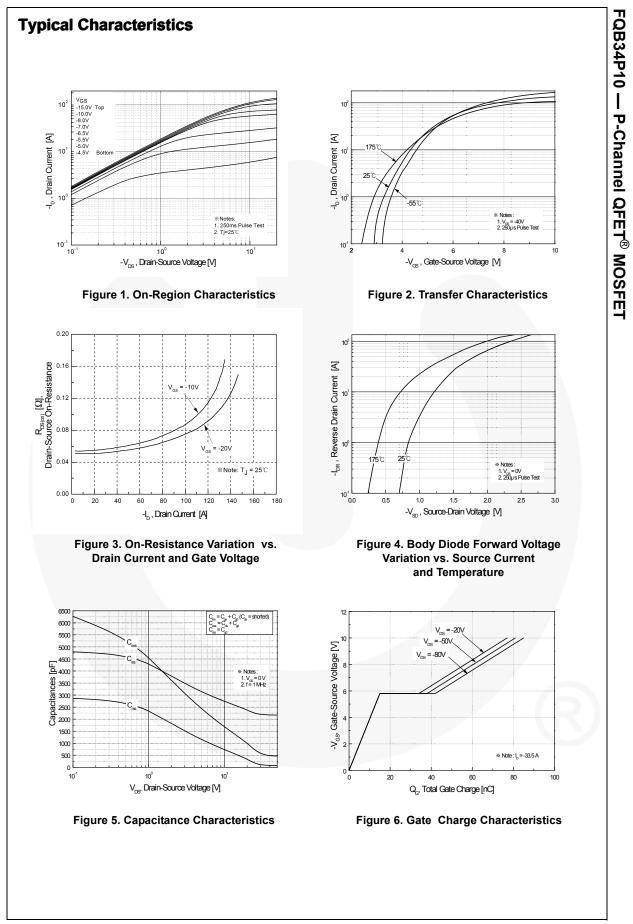
Absolute Maximum Ratings T_c = 25°C unless otherwise noted.

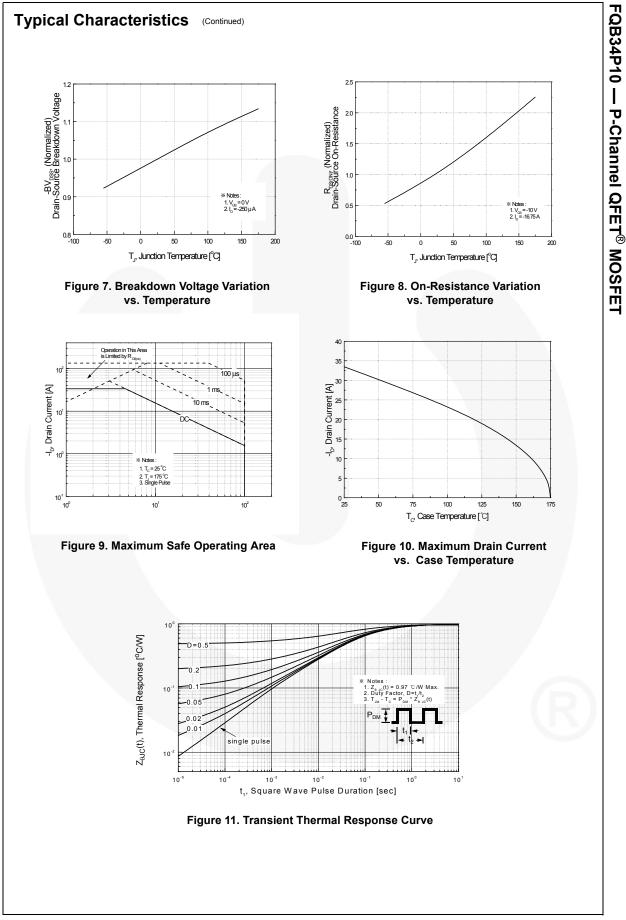
Symbol	Parameter		FQB34P10TM	Unit
V _{DSS}	Drain-Source Voltage		-100	V
I _D	Drain Current - Continuous ($T_C = 25^{\circ}C$)		-33.5	A
	- Continuous (T _C = 100°C)	-23.5	A	
I _{DM}	Drain Current - Pulsed	(Note 1)	-134	A
V _{GSS}	Gate-Source Voltage		± 25	V
E _{AS}	Single Pulsed Avalanche Energy	(Note 2)	2200	mJ
I _{AR}	Avalanche Current	(Note 1)	-33.5	A
E _{AR}	Repetitive Avalanche Energy	(Note 1)	15.5	mJ
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	-6.0	V/ns
P _D	Power Dissipation $(T_A = 25^{\circ}C)^*$		3.75	W
	Power Dissipation $(T_C = 25^{\circ}C)$		155	W
	- Derate above 25°C		1.03	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range	-55 to +175	°C	
TL	Maximum lead temperature for soldering, 1/8" from case for 5 seconds		300	°C

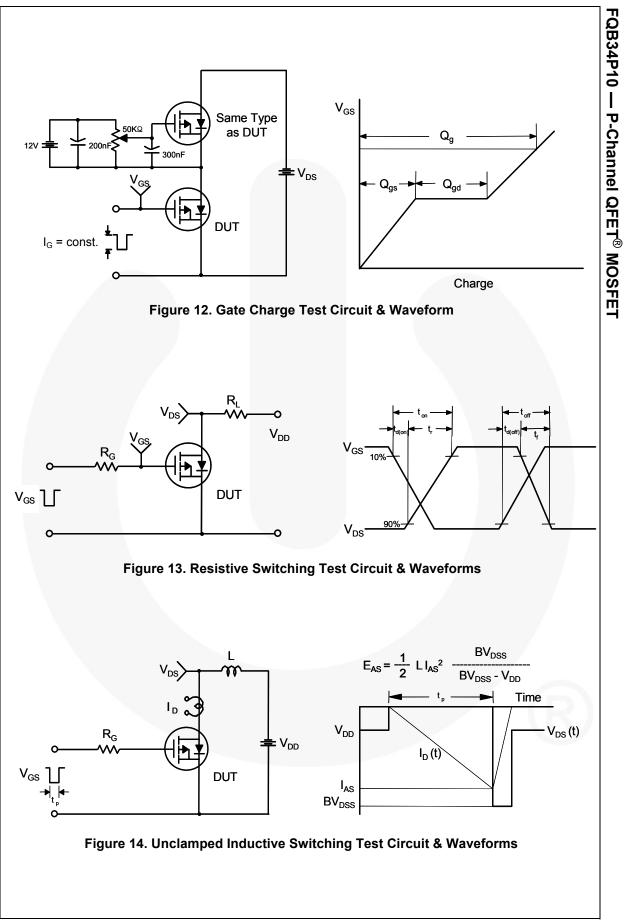
Thermal Characteristics

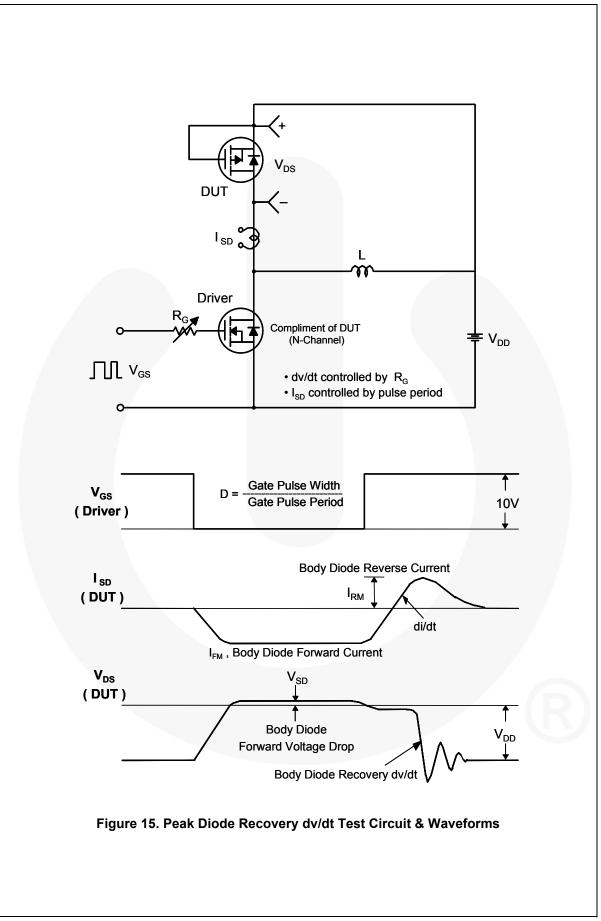
Symbol	Parameter	FQB34P10TM	Unit
R_{\thetaJC}	Thermal Resistance, Junction to Case, Max.	0.97	
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient (Minimum Pad of 2-oz Copper), Max.	62.5	°C/W
	Thermal Resistance, Junction to Ambient (*1 in ² Pad of 2-oz Copper), Max.	40]

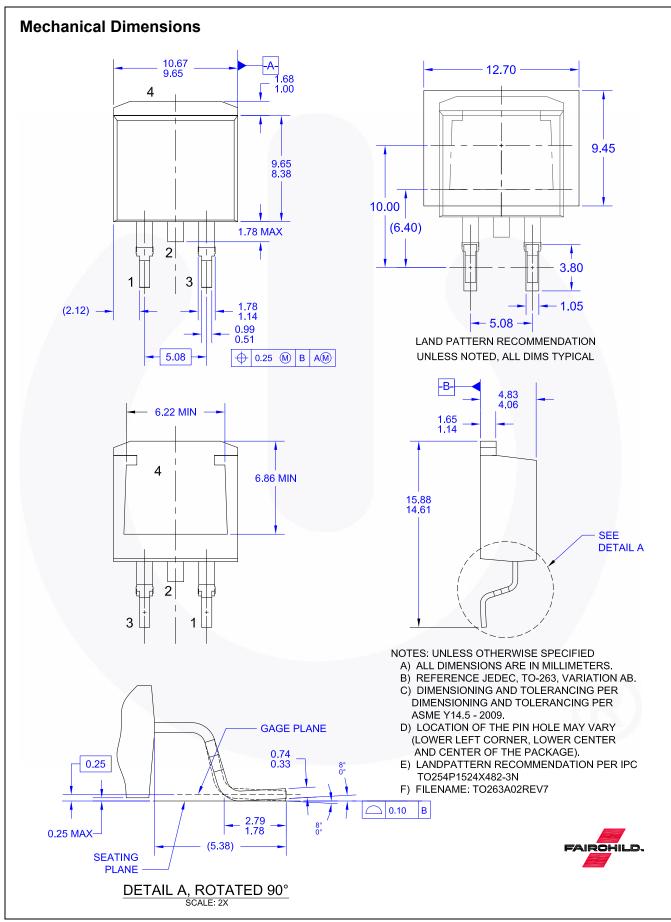
Part Number FQB34P10TM		Top Mark	Pack	age	Packing Method	Reel	Size	Tape Wi	dth C	Quantity
		FQB34P10	D ² -1	PAK	AK Tape and Reel		mm	24 mm		800 units
lectri	cal Cha	racteristics	T _C = 25°0	Cunless off	nerwise noted.					
Symbol		Parameter			Test Conditions		Min.	Тур.	Max.	Unit
Off Cha	aracterist	ice								
BV _{DSS}		Irce Breakdown Vo	Itage	V _{GS} =	0 V, I _D = -250 μA		-100			V
ΔBV _{DSS} /ΔTJ	Breakdow Coefficien	own Voltage Temperature		$I_D = -250 \ \mu\text{A}$, Referenced to 25°C			-0.1		V/°C	
DSS	Zero Gate Voltage Drain Current			-100 V, V _{GS} = 0 V				-1	μA	
			20	-80 V, T _C = 150°C				-10	μA	
GSSF	Gate-Bod	y Leakage Current	Forward	V_{GS} = -25 V, V_{DS} = 0 V					-100	nA
GSSR	Gate-Bod	y Leakage Current	Reverse	V _{GS} =	25 V, V _{DS} = 0 V				100	nA
On Cha	racterist	ics								
/ _{GS(th)}	Gate Thre	shold Voltage		V _{DS} =	V _{GS} , I _D = -250 μA		-2.0		-4.0	V
R _{DS(on)}	Static Dra On-Resist				-10 V, I _D = -16.75 A			0.049	0.06	Ω
ĴFS	Forward 1	ransconductance		V _{DS} =	-40 V, I _D = -16.75 A			23		S
Dynam	ic Chara	cteristics								
Siss	Input Cap		_	V	$-25 \sqrt{1} = 0 \sqrt{1}$			2240	2910	pF
Coss		apacitance	_	V _{DS} = -25 V, V _{GS} = 0 V, f = 1.0 MHz				730	950	pF
Prss		ansfer Capacitance					170	220	pF	
										1
d(on)		acteristics Delay Time	_					25	60	ns
a(on) r	Turn-On F	,	_	V _{DD} = -50 V, I _D = -33.5 A,				250	510	ns
d(off)		Delay Time	_	R _G = 2	25 Ω			160	330	ns
u(OII) f	Turn-Off F	,		-		(Note 4)		210	430	ns
λ _g	Total Gate			V -	-80 V, I _D = -33.5 A,			85	110	nC
Q_{gs}		rce Charge		V _{DS} =				15		nC
Ω _{gd}	Gate-Drai	5		•GS		(Note 4)		45		nC
							1	II		1
	1				cimum Ratings	-			00 5	
S		Continuous Drain-							-33.5	A
SM		Pulsed Drain-Sou			0 V, I _S = -33.5 A				-134	A
/ _{SD}		Irce Diode Forward	voltage		-				-4.0	V
rr C		Recovery Time		V _{GS} = 0 V, I _S = -33.5 A, dI _F / dt = 100 A/μs			160		ns	
2 _{rr}	Reverse F	Recovery Charge		ur _F / ut	_ 100 Λ/μδ			0.88		μC
$L = mH$, I_{A} $I_{SD} \le -33.5$	$_{\rm S}$ = -33.5A, V _{DD} 5 A, di/dt \leq 300	dth limited by maximum j $_{1} = -25 V, R_{G} = 25 \Omega$, star $A/\mu s$, $V_{DD} \leq BV_{DSS}$, st operating temperature.	ting T _J = 25°C							













TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

AccuPower™ AttitudeEngine™ Awinda® AX-CAP®* BitSiC™ Build it Now™ CorePLUS™ CorePOWER™ CROSSVOLT™ CTL™ Current Transfer Logic™ DEUXPEED® Dual Cool™ **EcoSPARK**[®] EfficentMax™ ESBC™

Fairchild[®] Fairchild Semiconductor[®] FACT Quiet Series[™] FACT[®] FastvCore[™] FETBench[™] FPS[™]

F-PFS™ FRFET® Global Power ResourceSM GreenBridge™ Green FPS™ Green FPS™ e-Series™ Gmax™ GTO™ IntelliMAX™ **ISOPLANAR™** Marking Small Speakers Sound Louder and Better™ MegaBuck™ MICROCOUPI FRTM MicroFET MicroPak™ MicroPak2™ MillerDrive™ MotionMax™ MotionGrid[®] MTi[®] MTx® **MVN**[®] mWSaver® OptoHiT™ **OPTOLOGIC**®

OPTOPLANAR[®] $(l)_{\mathbb{R}}$ Power Supply WebDesigner™ PowerTrench® PowerXS™ Programmable Active Droop™ QFET QS™ Quiet Series™ RapidConfigure™ тм Saving our world, 1mW/W/kW at a time™ SignalWise™ SmartMax™ SMART START™ Solutions for Your Success[™] SPM[®] STEALTH™ SuperFET[®] SuperSOT™-3 SuperSOT™-6 SuperSOT™-8 SupreMOS® SyncFET™ Sync-Lock™

SYSTEM ®* GENERAL TinyBoost[®] TinyBuck[®] TinyCalc™ TinyLogic® TIŃYOPTO™ TinyPower™ TinyPWM™ TinyWire™ TranSiC™ TriFault Detect™ TRUECURRENT®* μSerDes™ μ UHC® Ultra FRFET™ UniFET™ VCX™ VisualMax™ VoltagePlus™

XS™

Xsens™

仙童®

FQB34P10

I

P-Channel QFET[®] MOSFET

*Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. TO OBTAIN THE LATEST, MOST UP-TO-DATE DATASHEET AND PRODUCT INFORMATION, VISIT OUR WEBSITE AT <u>HTTP://WWW.FAIRCHILDSEMI.COM</u>. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

AUTHORIZED USE

Unless otherwise specified in this data sheet, this product is a standard commercial product and is not intended for use in applications that require extraordinary levels of quality and reliability. This product may not be used in the following applications, unless specifically approved in writing by a Fairchild officer: (1) automotive or other transportation, (2) military/aerospace, (3) any safety critical application – including life critical medical equipment – where the failure of the Fairchild product reasonably would be expected to result in personal injury, death or property damage. Customer's use of this product is subject to agreement of this Authorized Use policy. In the event of an unauthorized use of Fairchild's product, Fairchild accepts no liability in the event of product failure. In other respects, this product shall be subject to Fairchild's Worldwide Terms and Conditions of Sale, unless a separate agreement has been signed by by bth Parties.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Terms of Use

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition				
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.				
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.				
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.				
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.				

Rev. 177

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor has against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death ass

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC